IN THE CLAIMS

Please amend the claims as follows:

Claim 1 (Currently Amended): A method of facilitating a process performed by a semiconductor processing tool, comprising:

inputting a first principles physical model including a set of computer-encoded differential equations, the first principles physical model describing at least one of a basic physical or chemical attribute of the semiconductor processing tool and including 1) a spatially resolved model of a physical geometry of the semiconductor processing tool and 2) a grid set addressing the semiconductor processing tool or a geometry of the semiconductor processing tool;

inputting process data related to an actual process being performed by the semiconductor processing tool;

setting boundary conditions for the spatially resolved model of the physical geometry of the semiconductor processing tool based on said process data related to the actual process being performed by the semiconductor processing tool;

storing in a fab-level library known simulation results obtained from simulation modules in a device manufacturing fab and distributing the known simulation results to other semiconductor processing tools in the device manufacturing fab;

solving the computer-encoded differential equations of the first principles physical model for the spatially resolved model concurrently with the actual process being performed and in a time frame shorter in time than the actual process being performed to produce a first principles simulation by:

using code parallelization techniques on multiple simulation modules

in the device manufacturing fab, and

re-using known simulation solutions as initial conditions for the first

principles simulation,

wherein re-using known simulation solutions comprises searching in

the fab-level library for a closest fitting solution which if used for the initial

condition would reduce the number of iterations required by the simulation

module;

providing from the solution of the computer-encoded differential equations solved

concurrently with the actual process being performed a first principles simulation result; and

using the first principles simulation result obtained during the performance of the

actual process to facilitate the actual process being performed by the semiconductor

processing tool.

Claim 2 (Previously Presented): The method of Claim 1, wherein said inputting

process data comprises directly inputting the data relating to the actual process being

performed by the semiconductor processing tool from at least one of a physical sensor and a

metrology tool physically mounted on the semiconductor processing tool.

Claim 3 (Previously Presented): The method of Claim 1, wherein said inputting

process data comprises indirectly inputting the data relating to the actual process being

performed by the semiconductor processing tool from at least one of a manual input device

and a database.

Claim 4 (Original): The method of Claim 3, wherein said indirectly inputting

comprises inputting data recorded from a process previously performed by the semiconductor

processing tool.

Claim 5 (Original): The method of Claim 3, wherein said indirectly inputting comprises inputting data set by a simulation operator.

Claim 6 (Previously Presented): The method of Claim 1, wherein said inputting process data comprises inputting data relating to at least one of the physical characteristics of the semiconductor processing tool and the semiconductor tool environment.

Claim 7 (Previously Presented): The method of Claim 1, wherein said inputting process data comprises inputting data relating to at least one of a characteristic and a result of a process performed by the semiconductor processing tool.

Claim 8 (Cancelled).

Claim 9 (Original): The method of Claim 1, wherein said inputting a first principles physical model comprises inputting fundamental equations necessary to perform first principles simulation for a desired simulation result.

Claims 10-13 (Cancelled).

Claim 14 (Previously Presented): The method of Claim 1, further comprising using a network of interconnected resources inside a semiconductor device manufacturing facility to perform the first principles simulation recited in Claim 1.

Claim 15 (Original): The method of Claim 14, further comprising using code parallelization among interconnected computational resources to share the computational load of the first principles simulation.

Claim 16 (Original): The method of Claim 14, further comprising sharing simulation information among interconnected resources to facilitate a process performed by the semiconductor processing tool.

Claim 17 (Original): The method of Claim 16, wherein said sharing simulation information comprises distributing simulation results among the interconnected resources to reduce redundant execution of substantially similar first principles simulations by different resources.

Claim 18 (Original): The method of Claim 16, wherein said sharing simulation information comprises distributing model changes among the interconnected resources to reduce redundant refinements of first principles simulations by different resources.

Claim 19 (Previously Presented): The method of Claim 1, further comprising using remote resources via a wide area network to facilitate the semiconductor process performed by the semiconductor processing tool.

Claim 20 (Original): The method of Claim 19, wherein said using remote resources comprises using at least one of remote computational and storage resources via a wide area network to facilitate the semiconductor process performed by the semiconductor processing tool.

Claim 21 (Currently Amended): A system comprising:

a semiconductor processing tool configured to perform a process;

a fab-level library storing known simulation results obtained from simulation modules in a device manufacturing fab;

a fab-level process controller distributing the known simulation results to other semiconductor processing tools in the device manufacturing fab;

a first principles simulation processor configured to input a first principles physical model including a set of computer-encoded differential equations describing at least one of a basic physical or chemical attribute of the semiconductor processing tool and including 1) a spatially resolved model of a physical geometry of the semiconductor processing tool and 2) a grid set addressing the semiconductor processing tool or a geometry of the semiconductor processing tool;

an input device configured to input process data related to an actual process being performed by the semiconductor processing tool; and

said first principles simulation processor further configured to:

set boundary conditions for the spatially resolved model of the physical geometry of the semiconductor processing tool based on said process data related to the actual process being performed by the semiconductor processing tool,

solve the computer-encoded differential equations of the first principles physical model for the spatially resolved model concurrently with the actual process being performed and in a time frame shorter in time than the actual process being performed to produce a first principles simulation by:

using code parallelization techniques on multiple simulation modules

in the device manufacturing fab, and

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re-using known simulation solutions as initial conditions for the first

principles simulation,

wherein re-using known simulation solutions comprises searching in

the fab-level library for a closest fitting solution which if used for the initial

condition would reduce the number of iterations required by the simulation

module, and

provide from the solution of the computer-encoded differential equations solved

concurrently with the actual process being performed a first principles simulation result,

wherein said first principles simulation result obtained during the performance of the

actual process is used to facilitate the actual process being performed by the semiconductor

processing tool.

Claim 22 (Original): The system of Claim 21, wherein said input device comprises at

least one of a physical sensor and a metrology tool physically mounted on the semiconductor

processing tool.

Claim 23 (Original): The system of Claim 21, wherein said input device comprises at

least one of a manual input device and a database.

Claim 24 (Original): The system of Claim 23, wherein said input device is configured

to input data recorded from a process previously performed by the semiconductor processing

tool.

Claim 25 (Original): The system of Claim 23, wherein said input device is configured

to input data set by a simulation operator.

Claim 26 (Original): The system of Claim 21, wherein said input device is configured to input data relating to at least one of the physical characteristics of the semiconductor processing tool and the semiconductor tool environment.

Claim 27 (Original): The system of Claim 21, wherein said input device is configured to input data relating to at least one of a characteristic and a result of a process performed by the semiconductor processing tool.

Claim 28 (Cancelled).

Claim 29 (Original): The system of Claim 21, wherein said processor is configured to input a first principles physical model comprising fundamental equations necessary to perform first principles simulation for a desired simulation result.

Claims 30-33 (Cancelled).

Claim 34 (Previously Presented): The system of Claim 21, further comprising a network of interconnected resources inside a semiconductor device manufacturing facility and connected to said processor and configured to assist said processor in performing at least one of the inputting a first principles simulation model and performing a first principles simulation.

Claim 35 (Original): The system of Claim 34, wherein said network of interconnected resources is configured to use code parallelization with said processor to share the computational load of the first principles simulation.

Claim 36 (Original): The system of Claim 34, wherein said network of interconnected resources is configured to share simulation information with said processor to facilitate said process performed by the semiconductor processing tool.

Claim 37 (Original): The system of Claim 36, wherein said network of interconnected resources is configured to distribute simulation results to said processor to reduce redundant execution of substantially similar first principles simulations.

Claim 38 (Original): The system of Claim 36, wherein said network of interconnected resources is configured to distribute model changes to said processor to reduce redundant refinements of first principles simulations.

Claim 39 (Previously Presented): The system of Claim 21, further comprising remote resources connected to said processor via a wide area network and configured to facilitate the semiconductor process performed by the semiconductor processing tool.

Claim 40 (Original): The system of Claim 39, wherein said remote resources comprise at least one of a computational and a storage resource.

Claims 41-43 (Cancelled).

Claim 44 (Currently Amended):   At least one of non-volatile media and volatile

media containing program instructions for execution on a processor, which when executed by

the computer system, cause the processor to perform the steps of:

inputting a first principles physical model including a set of computer-encoded

differential equations, the first principles physical model describing at least one of a basic

physical or chemical attribute of the semiconductor processing tool and including 1) a

spatially resolved model of a physical geometry of the semiconductor processing tool and 2)

a grid set addressing the semiconductor processing tool or a geometry of the semiconductor

processing tool;

inputting process data related to an actual process being performed by the

semiconductor processing tool;

setting boundary conditions for the spatially resolved model of the physical geometry

of the semiconductor processing tool based on said process data related to the actual process

being performed by the semiconductor processing tool;

storing in a fab-level library known simulation results obtained from simulation

modules in a device manufacturing fab and distributing the known simulation results to other

semiconductor processing tools in the device manufacturing fab;

solving the computer-encoded differential equations of the first principles physical

model for the spatially resolved model concurrently with the actual process being performed

and in a time frame shorter in time than the actual process being performed to produce a first

principles simulation by:

using code parallelization techniques on multiple simulation modules

in the device manufacturing fab, and

re-using known simulation solutions as initial conditions for the first

principles simulation,

wherein re-using known simulation solutions comprises searching in

the fab-level library for a closest fitting solution which if used for the initial

condition would reduce the number of iterations required by the simulation

module;

providing from the solution of the computer-encoded differential equations solved

concurrently with the actual process being performed a first principles simulation result; and

using the first principles simulation result obtained during the performance of the

actual process to facilitate the actual process being performed by the semiconductor

processing tool.

Claim 45-47 (Cancelled).